





	<h2 style="color: red;">FQB2N60TM</h2>
 <p>Image may be representation. See specs for product details.</p>	Hersteller-Teilenummer: FQB2N60TM
	Hersteller / Marke: AMI Semiconductor / ON Semiconductor
	Teil der Beschreibung: MOSFET N-CH 600V 2.4A D2PAK
	Datenblätter:  FQB2N60TM.pdf
	RoHs Status: Bleifrei / RoHS-konform
	Lagerzustand: New original, 580 pcs Stock Available.
Liefern von: Hong Kong	
Versandweg: DHL/Fedex/TNT/UPS/EMS	

Spezifikationen

Teilenummer	FQB2N60TM
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET N-CH 600V 2.4A D2PAK
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	580 pcs Stock
detaillierte Beschreibung	N-Channel 600V 2.4A (Tc) 3.13W (Ta), 64W (Tc)
Serie	QFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-263-3, D ² Pak (2 Leads + Tab), TO-263AB
Supplier Device-Gehäuse	D ² PAK (TO-263AB)
Verlustleistung (max)	3.13W (Ta), 64W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	600V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	2.4A (Tc)
Rds On (Max) @ Id, Vgs	4.7 Ohm @ 1.2A, 10V
VGS (th) (Max) @ Id	5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	11nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	350pF @ 25V
Antriebsspannung (Max Rds On, Min Rds On)	10V
Vgs (Max)	±30V
Verpackung	Tape & Reel (TR)
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)












































FQB2N60TM ist neu im Original, Suche FQB2N60TM Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FQB2N60TM AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage FQB2N60TM: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>FQB2N50TM Fairchild/ON Semiconductor MOSFET N-CH 500V 2.1A D2PAK</p>	 <p>FQB2N80TM Fairchild/ON Semiconductor MOSFET N-CH 800V 2.4A D2PAK</p>	 <p>FQB2N50TM AMI Semiconductor / ON Semiconductor MOSFET N-CH 500V 2.1A D2PAK</p>	 <p>FQB2N50C VB FQB2N50C VB</p>
 <p>FQB2N90TM Fairchild/ON Semiconductor MOSFET N-CH 900V 2.2A D2PAK</p>	 <p>FQB2N60 FAIRCHILD FQB2N60 FAIRCHILD</p>	 <p>FQB2N80TM AMI Semiconductor / ON Semiconductor MOSFET N-CH 800V 2.4A D2PAK</p>	 <p>FQB2N60TM Fairchild/ON Semiconductor MOSFET N-CH 600V 2.4A D2PAK</p>

heiße Teile

Mehr

 FQB19N20LTM	 FQB19N20LTM	 FQB19N20TM	 FQB19N20TM	 FQB19N20TM
 FQB1N60TM	 FQB20N06L	 FQB20N60FTM	 FQB20N60TM	 FQB22P10
 FQB22P10TM	 FQB22P10TM	 FQB22P10TM_F085	 FQB24N08TM	 FQB24N08TM
 FQB25N33	 FQB25N33TM	 FQB25N33TM	 FQB25N33TM_F085	 FQB27N25TM
 FQB27P06	 FQB27P06TM	 FQB27P06TM	 FQB2N50C	 FQB2N60TM
 FQB2N80TM	 FQB2N80TM	 FQB2NA90TM	 FQB2NA90TM	 FQB2P25TM
 FQB2P25TM	 FQB30N06	 FQB30N06L	 FQB30N06LTM	 FQB30N06LTM
 FQB30N06TM	 FQB30N06TM	 FQB32N12V2	 FQB32N12V2TM	 FQB32N12V2TM
 FQB32N20	 FQB32N20C	 FQB32N20CTM	 FQB32N20CTM	 FQB32N30
 FQB33N10	 FQB33N10L	 FQB33N10LTM	 FQB33N10LTM	 FQB33N10TM

Contact us:Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

Copyright © 2019 YIC International Co., Limited